

INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Not for submission under 37 CFR 1.99)	Application Number		10758966	
	Filing Date		2004-01-16	
	First Named Inventor	DIANE K. STEWART		
	Art Unit	1792		
	Examiner Name	ALLAN W. OLSEN		
	Attorney Docket Number	F125		

U.S.PATENTS						
Examiner Initial*	Cite No	Patent Number	Kind Code ¹	Issue Date	Name of Patentee or Applicant of cited Document	Pages,Columns,Lines where Relevant Passages or Relevant Figures Appear
	1	5639699		1997-06-17	NAKAMURA ET AL.	
	2	5965301		1999-10-12	NARA ET AL.	
	3	6361904		2002-03-26	CHIU	

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	1	NAKAMURA, H. ET AL., "Focused Ion Beam Assisted Etching of Quartz in XeF2 without Transmittance Reduction for Phase Shifting Mask Repair," Japanese Journal of Applied Physics, December 1992, pages 4465-4467, Volume 31, No. 12B, Japan.	<input type="checkbox"/>

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Examiner Signature	/Allan Olsen/	Date Considered	02/04/2010
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